

N-CHANNEL ENHANCEMENT MODE POWER MOSFET

MAIN CHARACTERISTICS

I_D	5A
V_{DSS}	500V
$R_{DS(ON)-typ}(@V_{GS}=10V)$	1.39Ω

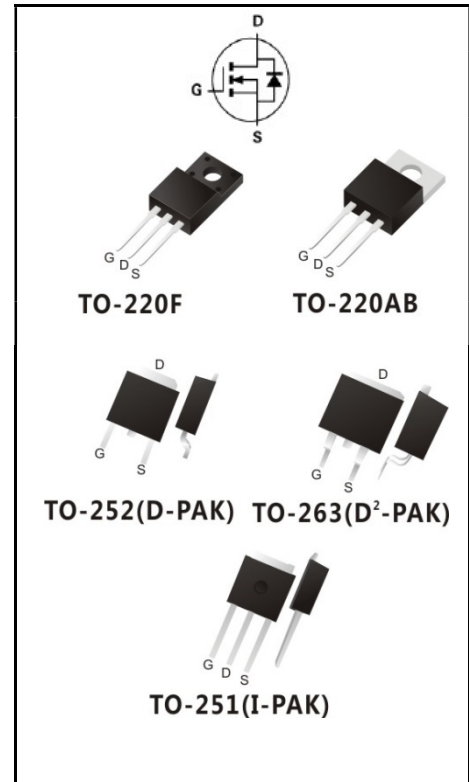


FEATURES

- ◆Fast Switching
- ◆Low ON Resistance
- ◆Low Gate Charge
- ◆100% Single Pulse avalanche energy Test
- ◆LeadfreeincomplywithEUroHS2011/65/EUdirectives

MECHANICAL DATA

- ◆Case: Molded plastic
- ◆Mounting Position: Any
- ◆Molded Plastic: UL Flammability Classification Rating 94V-0
- ◆Solder bath temperature275°C maximum,10s per JESD22-106
- ◆Case:TO-220AB, TO-220F, TO-263, TO-252, TO-251



PRODUCT SPECIFICATION CLASSIFICATION

Part Number	Package	Marking	Pack
YFW5N50A1	TO-220AB	5N50AT	50PCS/Tube
YFW5N50A2	TO-220F(0.5mm)	5N50AF	50PCS/Tube
YFW5N50A3	TO-263	5N50AS	50PCS/Tube
YFW5N50A3-R	TO-263	5N50AS	800PCS/Tape
YFW5N50A4	TO-251	5N50AMJ	80PCS/Tube
YFW5N50A5-R	TO-252	5N50AD	2500PCS/Tape

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbols	Value			Units
		220AB/263	220F	251/252	
Drain-Source Voltage	V_{DS}	500			V
Gate-Source Voltage	V_{GS}	±30			V
Continue Drain Current	I_D	5			A
- Continuous(Tc=100°C)		3.1			
Pulsed Drain Current (Note1)	I_{DM}	20			A
Power Dissipation	P_D	75	33	63	W
-Derate above 25°C		0.56	0.33	0.62	W/°C
Single Pulse Avalanche Energy (Note2)	E_{AS}	195			mJ
Avalanche Current (Note 1)	I_{AR}	5			A
Repetitive Avalanche Energy (Note 1)	E_{AR}	10.1			mJ
Operating Temperature Range	T_J	150			°C
Storage Temperature Range	T_{STG}	-55 to +150			°C
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.65	3.46	2.25	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	62.5	62.5	°C/W

Maximum Ratings at Tc=25°C unless otherwise specified

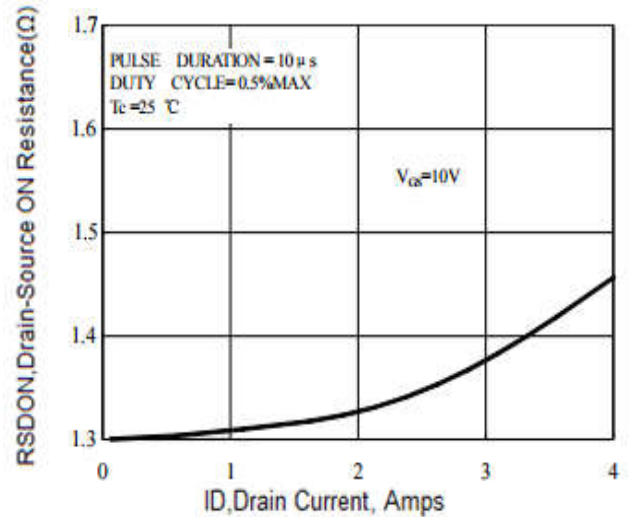
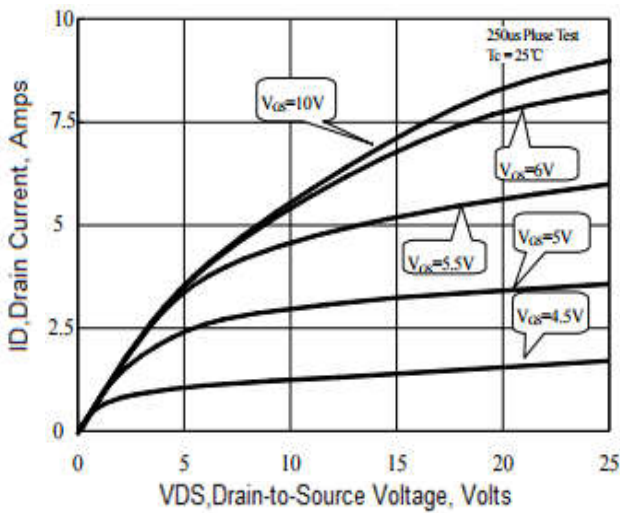
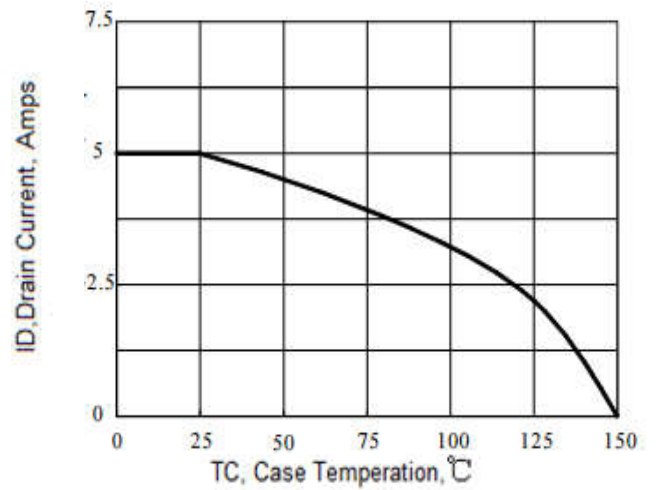
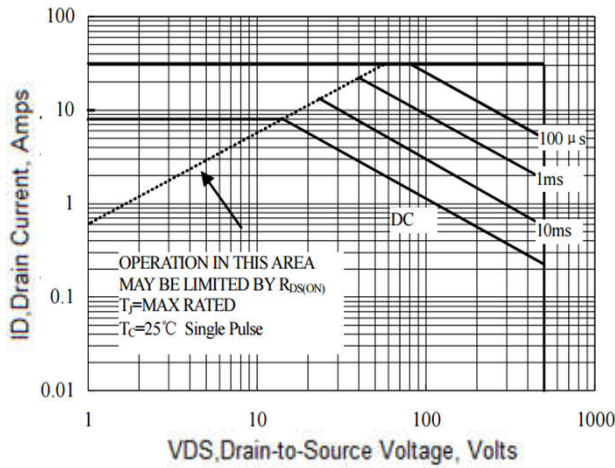
Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	BV_{DSS}	500	-	-	V
Drain-Source Leakage Current	$V_{DS} = 500 V, V_{GS} = 0 V$	I_{DSS}	-	-	1	uA
	$V_{DS}=400V, T_C=125^\circ C$		-	-	10	
Gate Leakage Current	$V_{GS} = \pm 30 V, V_{DS} = 0 V$	I_{GSS}	-	-	±100	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	$V_{GS} = 10 V, I_D = 2.5 A$	$R_{DS(on)}$	-	1.39	1.5	Ω
Forward Transconductance	$V_{DS} = 15 V, I_D = 2.5 A$	g_{fs}	-	4	-	S
Input Capacitance	$V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz$	C_{iss}	-	545	-	pF
Output Capacitance		C_{oss}	-	63	-	
Reverse Transfer Capacitance		C_{rss}	-	5.5	-	
Turn-on Delay Time	$I_D = 5 A, V_{DD} = 250 V, R_G = 10 \Omega (Note 3.4)$	$td(ON)$	-	9	-	nS
Rise Time		tr	-	11	-	
Turn-Off Delay Time		$td(OFF)$	-	29	-	
Fall Time		tf	-	16	-	
Total Gate Charge	$I_D = 5 A, V_{DD} = 400 V, V_{GS} = 10 V (Note 3.4)$	Q_G	-	14.5	-	nC
Gate to Source Charge		Q_{GS}	-	3.5	-	
Gate to Drain Charge		Q_{GD}	-	7	-	

Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

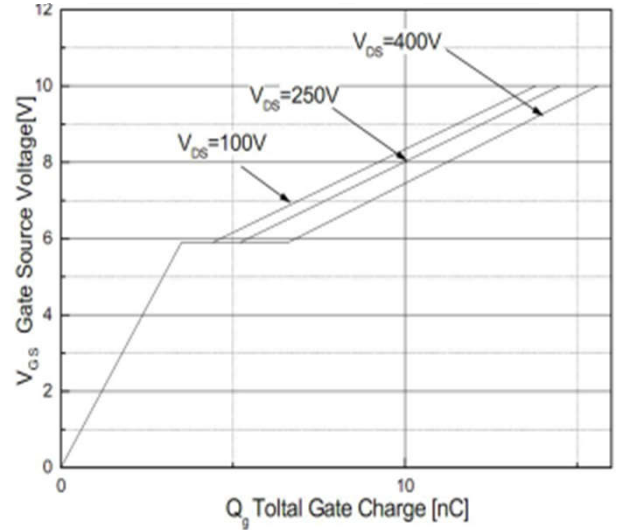
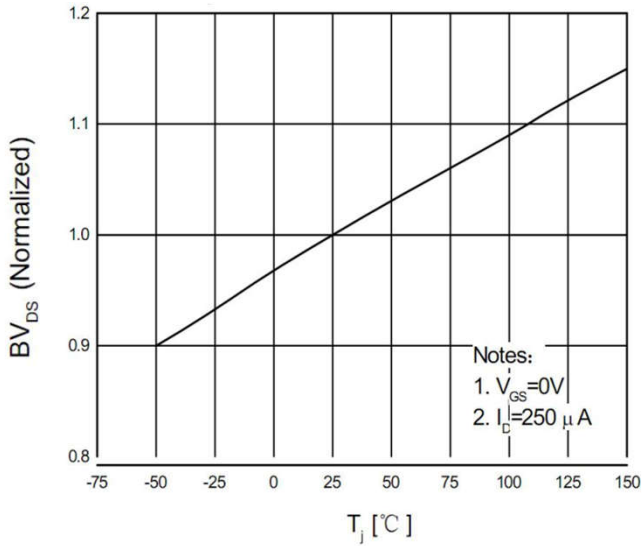
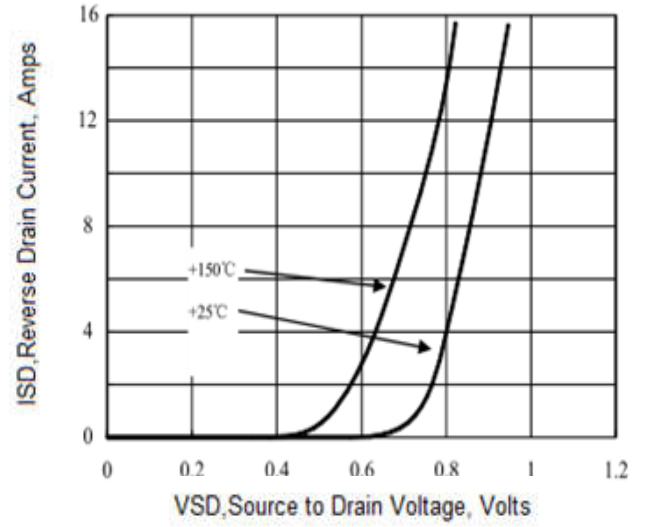
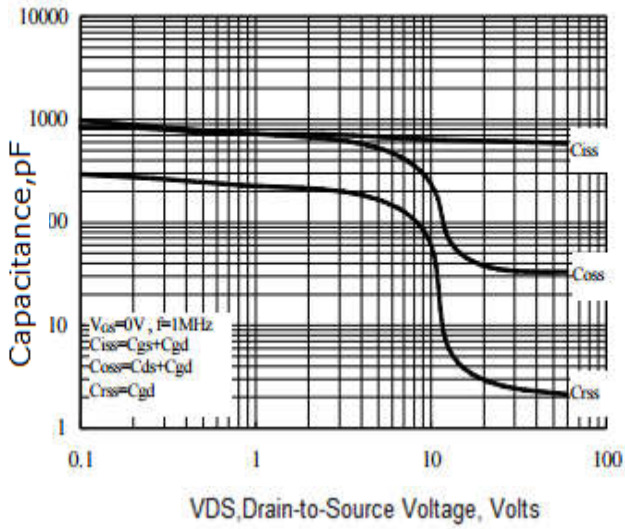
Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Maximun Body-Diode Continuous Current		I_S	-	-	5	A
Maximun Body-Diode Pulsed Current(Note2)		I_{SM}	-	-	20	A
Drain-Source Diode Forward Voltage	I _{SD} = 5 A	V_{SD}	-	-	1.4	V
Reverse Recovery Time	I _{SD} = 5 A, V _{GS} = 0 V, dI _F / dt = 100 A/μs	trr	-	391	-	nS
Reverse Recovery Charge		Qrr	-	1.7	-	uC

- Note:
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
 2. IAS = 5 A, VDD = 50 V, L = 16mH, RG = 25Ω, starting TJ = 25°C.
 3. ulse test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.
 4. Essentially Independent of Operating Temperature.

RATINGS AND CHARACTERISTIC CURVES



RATINGS AND CHARACTERISTIC CURVES



Package Outline Dimensions millimeters

TO-220AB

	Dim.	Min.	Max.
	A	10.15	10.35
	B	2.65	2.95
	C	3.70	3.90
	D	28.5	29.5
	E	1.30	1.45
	F	6.35	6.55
	G	2.9	3.3
	H	15.0	16.0
	I	0.38	0.42
	J	4.45	4.55
	K	1.25	1.35
	L	Typ 5.08	
	M	Typ 2.54	
N	3.1	3.3	
O	0.76	0.84	
All Dimensions in millimeter			

TO-220F

	Dim.	Min.	Max.
	A	9.95	10.25
	B	2.95	3.25
	C	1.25	1.45
	D	12.95	13.25
	E	0.50	0.65
	F	3.1	3.3
	G	1.30	1.45
	H	Typ 2.54	
	I	Typ 5.08	
	J	4.60	4.75
	K	2.50	2.65
	L	6.35	6.55
	M	15.4	16.0
N	2.75	3.05	
O	0.48	0.52	
P	0.76	0.84	
All Dimensions in millimeter			

Package Outline Dimensions millimeters

TO-263

	Dim.	Min.	Max.
	A	10.1	10.2
	B	7.4	7.6
	C	1.3	1.5
	D	0.55	0.75
	E	5.0	6.0
	F	1.4	1.6
	G	0.78	0.86
	H	1.2	1.3
	I	Typ2.54	
	J	8.4	8.6
	K	4.45	4.55
	L	1.25	1.35
	M	0.02	0.1
N	2.4	2.8	
O	0.36	0.40	
All Dimensions in millimeter			

TO-252

	Dim.	Min.	Max.
	A	2.1	2.5
	B	0.95	1.55
	C	0.4	0.6
	D	6.4	6.7
	D1	5.1	5.8
	E	5.8	6.4
	E1	Typ 2.3	
	E2	Typ 4.6	
	B1	0.6	0.8
	B2	0.75	0.95
	O	--	0.15
	L1	9.0	11.0
	L2	1.3	1.7
L3	0.70	0.95	
All Dimensions in millimeter			

Package Outline Dimensions millimeters

TO-251

	Dim.	Min.	Max.
	A	2.2	2.4
	A2	0.95	1.15
	A3	0.45	0.65
	b	0.65	0.85
	c	0.45	0.55
	D	6.45	6.75
	D2	5.2	5.4
	E	5.8	6
	E2	0.95	1.25
	e	Typ 2.3	
	e1	Typ 4.6	
	L	4	4.2
	L1	1.2	1.5
All Dimensions in millimeter			